

| | |
|--------------------|------|
| V_{DSS} | -12V |
| $R_{DS(on)(Max.)}$ | 23mΩ |
| I_D | ±6A |
| P_D | 1.5W |

●Features

- 1) Low on - resistance.
- 2) -1.5V Drive
- 3) Built-in G-S protection diode.
- 4) Small surface mount package(TSMT8).
- 5) Pb-free lead plating ; RoHS compliant

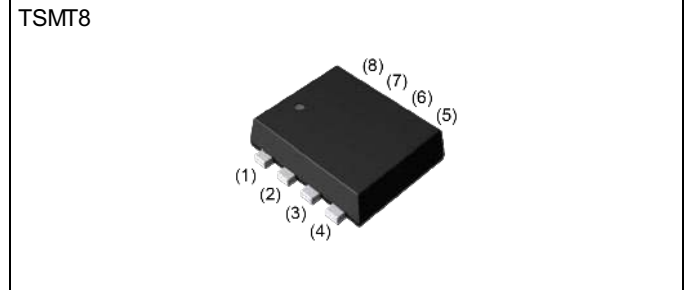
●Application

Switching

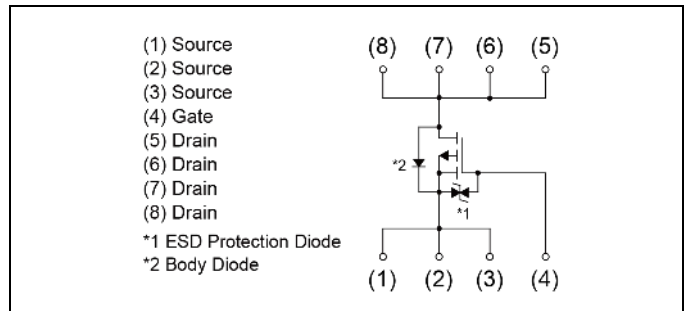
●Absolute maximum ratings ($T_a = 25^{\circ}C$)

| Parameter | Symbol | Value | Unit |
|------------------------------|--------------------|-------------|------|
| Drain - Source voltage | V_{DSS} | -12 | V |
| Continuous drain current | I_D | ±6 | A |
| Pulsed drain current | $I_{D,pulse}^{*1}$ | ±24 | A |
| Gate - Source voltage | V_{GSS} | ±10 | V |
| Power dissipation | P_D^{*2} | 1.5 | W |
| | P_D^{*3} | 0.7 | W |
| Junction temperature | T_j | 150 | °C |
| Range of storage temperature | T_{stg} | -55 to +150 | °C |

●Outline



●Inner circuit



●Packaging specifications

| Type | Packing | Embossed Tape |
|------|---------------------------|---------------|
| | Reel size (mm) | 180 |
| | Tape width (mm) | 8 |
| | Basic ordering unit (pcs) | 3000 |
| | Taping code | TR |
| | Marking | YH |

● Thermal resistance

| Parameter | Symbol | Values | | | Unit |
|--|-----------------|--------|------|------|------|
| | | Min. | Typ. | Max. | |
| Thermal resistance, junction - ambient | R_{thJA}^{*2} | - | - | 83.3 | °C/W |
| | R_{thJA}^{*3} | - | - | 178 | °C/W |

● Electrical characteristics ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Conditions | Values | | | Unit |
|--|---|--|--------|-------|----------|---------------|
| | | | Min. | Typ. | Max. | |
| Drain - Source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = -1mA$ | -12 | - | - | V |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$ | $I_D = -1mA$ referenced to 25°C | - | -21.9 | - | mV/°C |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = -12V, V_{GS} = 0V$ | - | - | -1 | μA |
| Gate - Source leakage current | I_{GSS} | $V_{GS} = \pm 10V, V_{DS} = 0V$ | - | - | ± 10 | μA |
| Gate threshold voltage | $V_{GS(th)}$ | $V_{DS} = -6V, I_D = -1mA$ | -0.3 | - | -1.0 | V |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{GS(th)}}{\Delta T_j}$ | $I_D = -1mA$ referenced to 25°C | - | 2.4 | - | mV/°C |
| Static drain - source on - state resistance | $R_{DS(on)}^{*4}$ | $V_{GS} = -4.5V, I_D = -6A$ | - | 16 | 23 | m Ω |
| | | $V_{GS} = -2.5V, I_D = -3A$ | - | 22 | 31 | |
| | | $V_{GS} = -1.8V, I_D = -3A$ | - | 28 | 42 | |
| | | $V_{GS} = -1.5V, I_D = -1.2A$ | - | 39 | 78 | |
| Gate input resistance | R_G | $f = 1MHz, \text{open drain}$ | - | 20 | - | Ω |
| Forward Transfer Admittance | $ Y_{fs} ^{*4}$ | $V_{DS} = -6V, I_D = -6A$ | 7.5 | - | - | S |

*1 $P_w \leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

*2 Mounted on a ceramic board (30×30×0.8mm)

*3 Mounted on a FR4 (20×20×0.8mm)

*4 Pulsed

●Electrical characteristics (T_a = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|------------------------------|-----------------------------------|--|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 2800 | - | pF |
| Output capacitance | C _{oss} | V _{DS} = -6V | - | 340 | - | |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 310 | - | |
| Turn - on delay time | t _{d(on)} ^{*4} | V _{DD} ≈ -6V, V _{GS} = -4.5V | - | 12 | - | ns |
| Rise time | t _r ^{*4} | I _D = -3A | - | 105 | - | |
| Turn - off delay time | t _{d(off)} ^{*4} | R _L ≈ 2Ω | - | 400 | - | |
| Fall time | t _f ^{*4} | R _G = 10Ω | - | 230 | - | |

●Gate charge characteristics (T_a = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------|-------------------------------|-------------------------|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| Total gate charge | Q _g ^{*4} | V _{DD} ≈ -6V, | - | 34 | - | nC |
| Gate - Source charge | Q _{gs} ^{*4} | I _D = -6A, | - | 6.0 | - | |
| Gate - Drain charge | Q _{gd} ^{*4} | V _{GS} = -4.5V | - | 5.0 | - | |

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|---------------------------------------|-------------------------------|--|--------|------|------|------|
| | | | Min. | Typ. | Max. | |
| Body diode continuous forward current | I _S | T _a = 25°C | - | - | -1 | A |
| Body diode pulse current | I _{SP} ^{*1} | | - | - | -24 | A |
| Forward voltage | V _{SD} ^{*4} | V _{GS} = 0V, I _S = -6A | - | - | -1.2 | V |

● Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

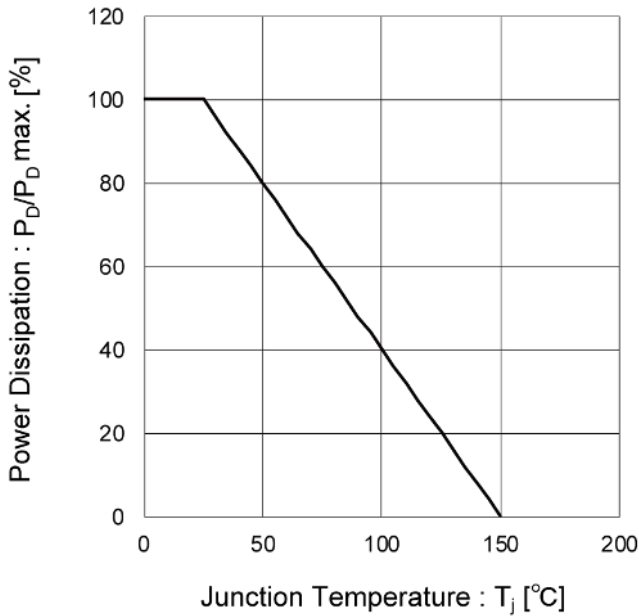


Fig.2 Maximum Safe Operating Area

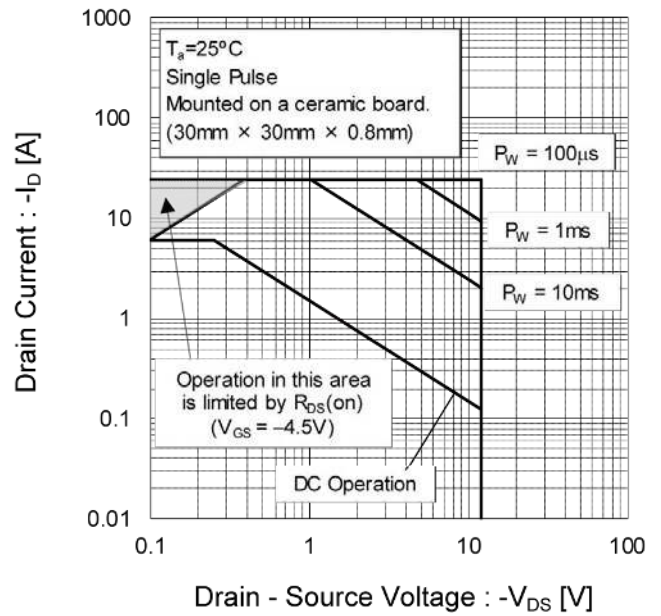


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

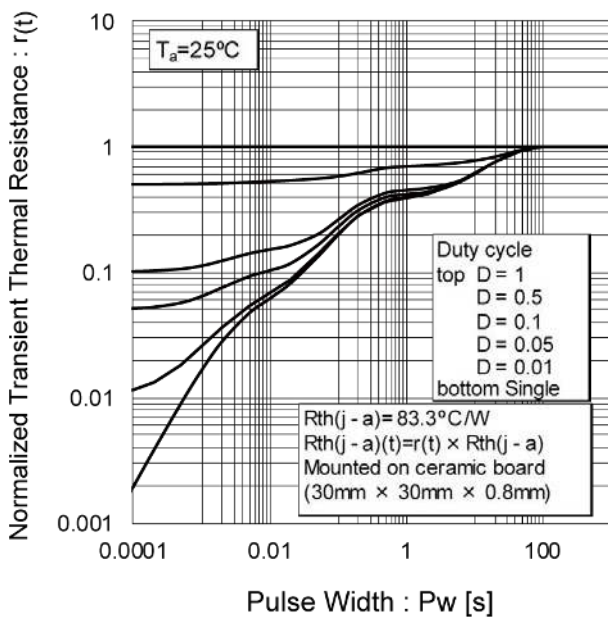
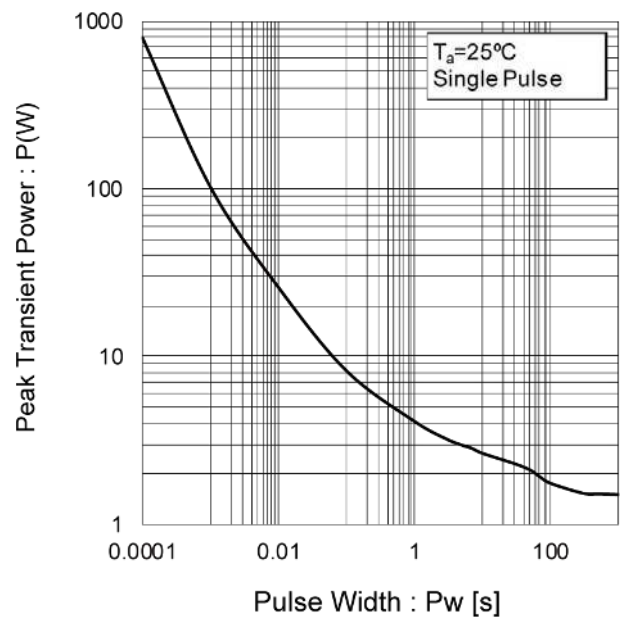


Fig.4 Single Pulse Maximum Power dissipation



● Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

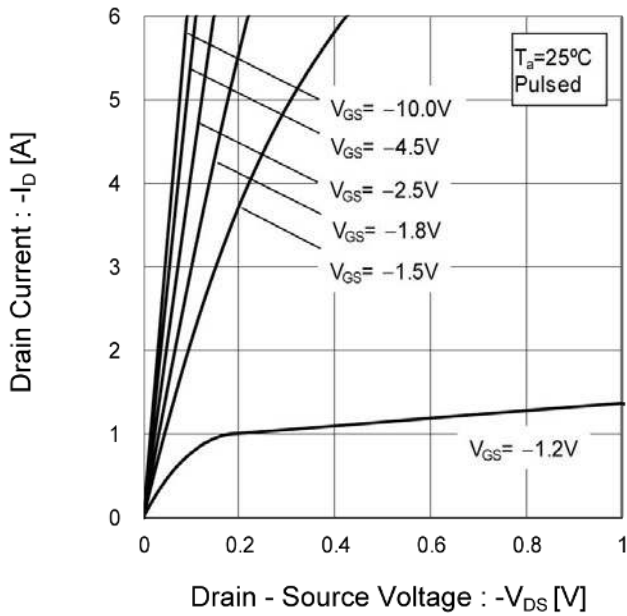


Fig.6 Typical Output Characteristics(II)

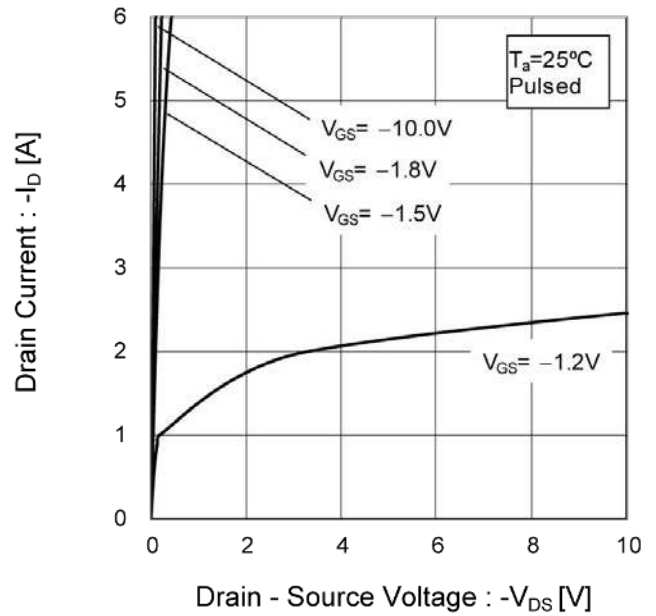


Fig.7 Breakdown Voltage vs. Junction Temperature

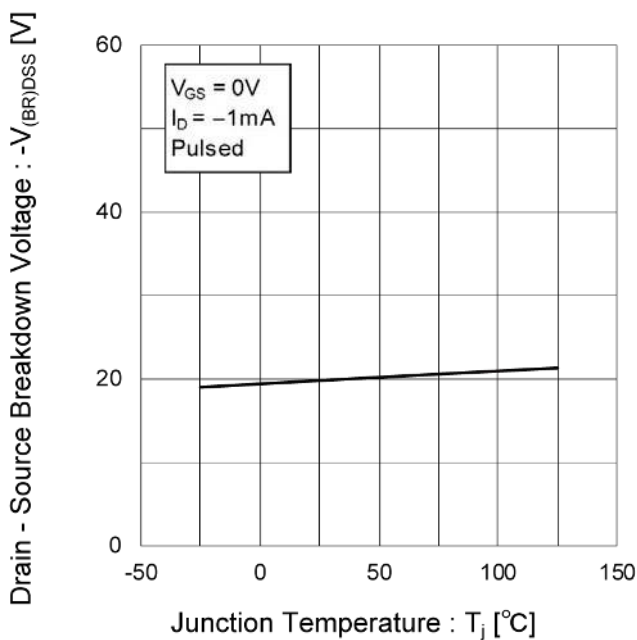
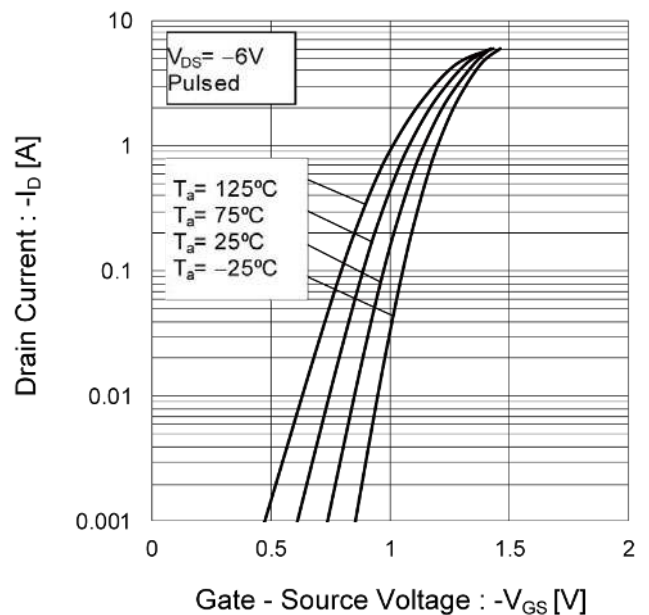


Fig.8 Typical Transfer Characteristics



● Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs. Junction Temperature

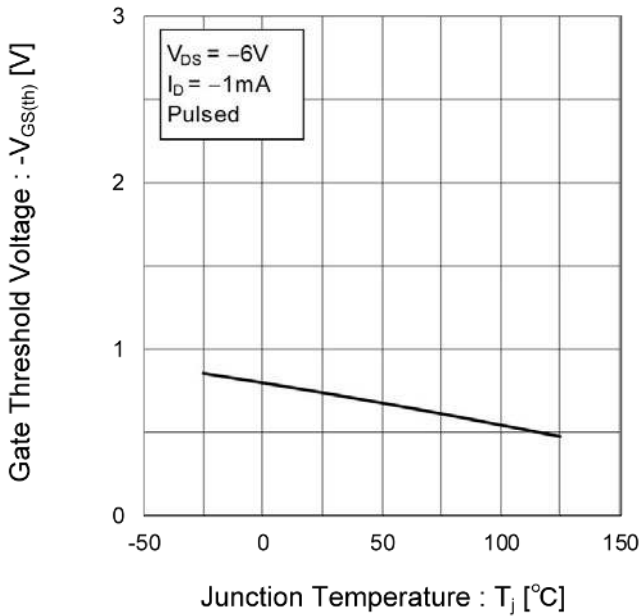


Fig.10 Forward Transfer Admittance vs. Drain Current

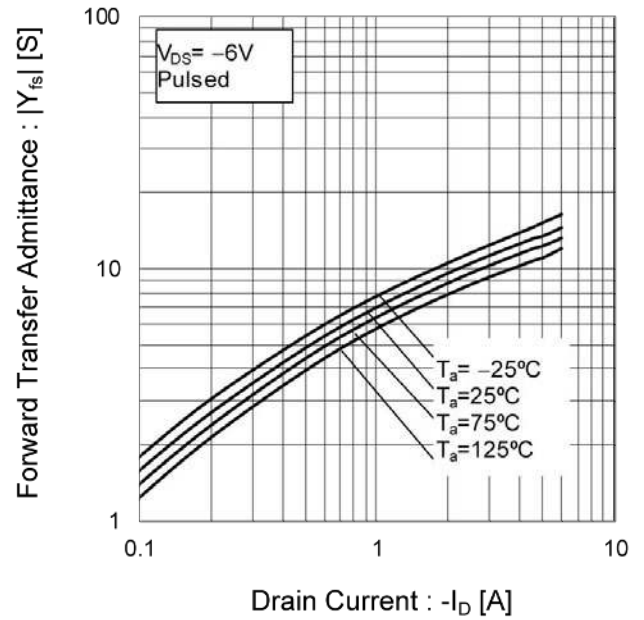


Fig.11 Drain Current Derating Curve

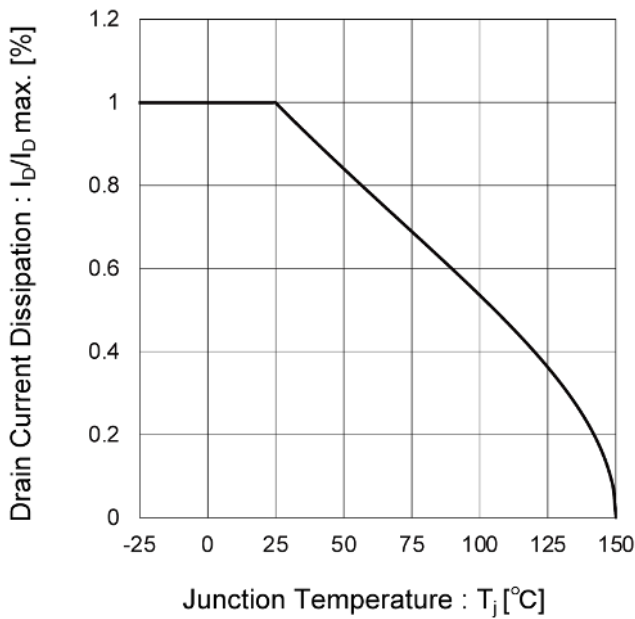
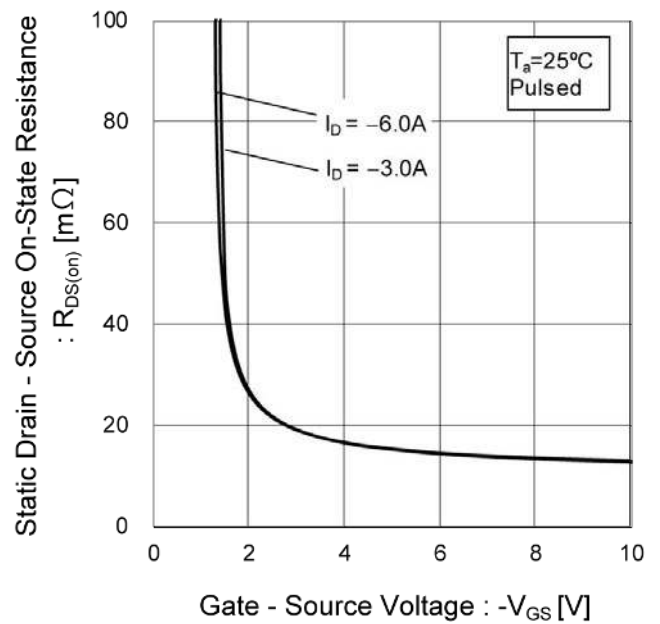


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



● Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

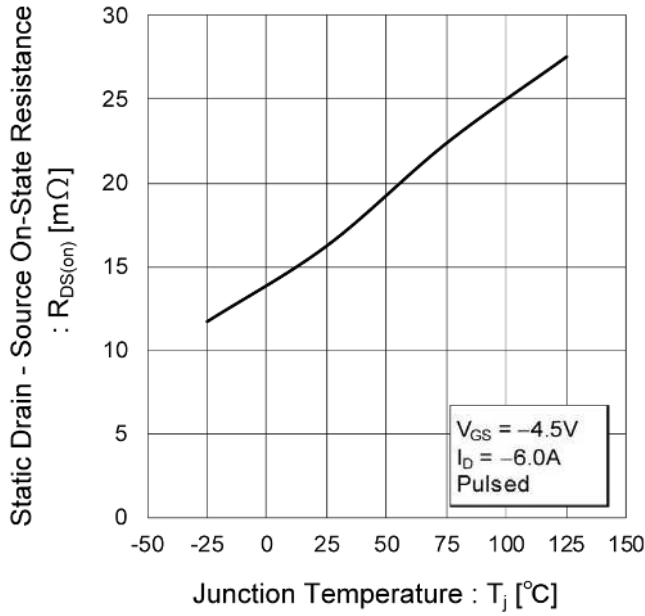
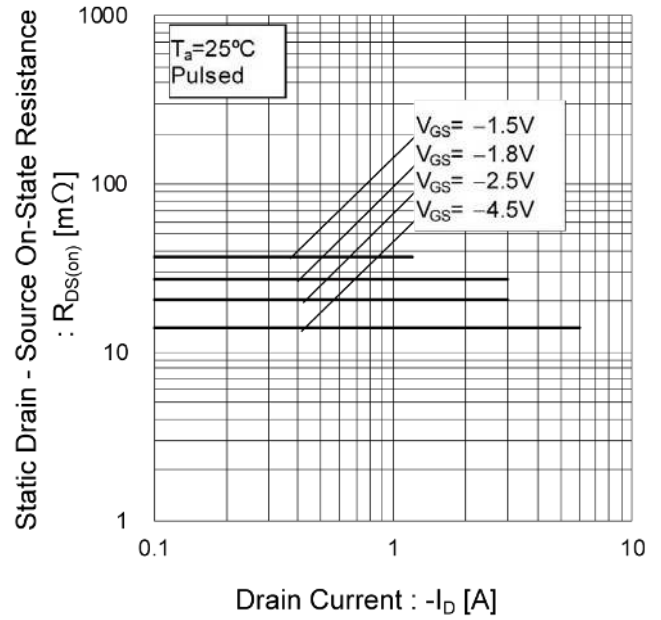


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)



● Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

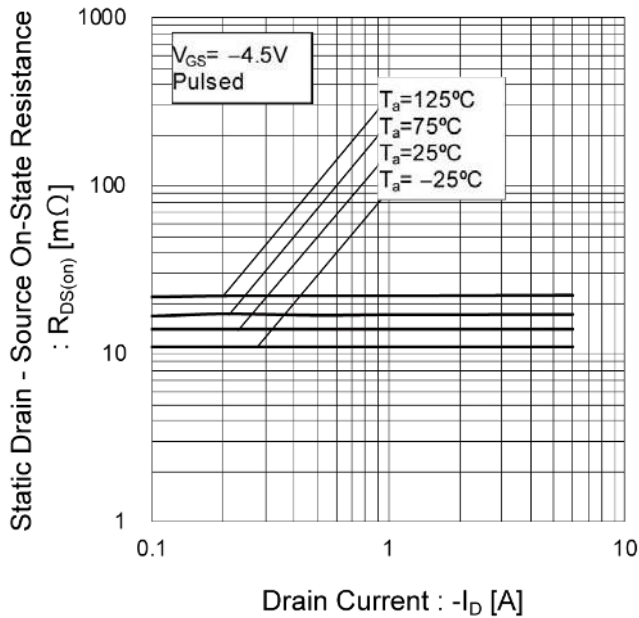


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

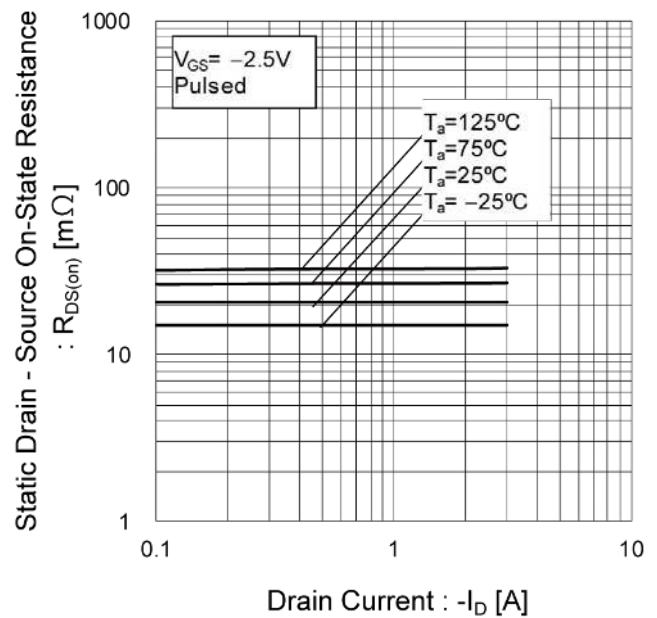


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current (IV)

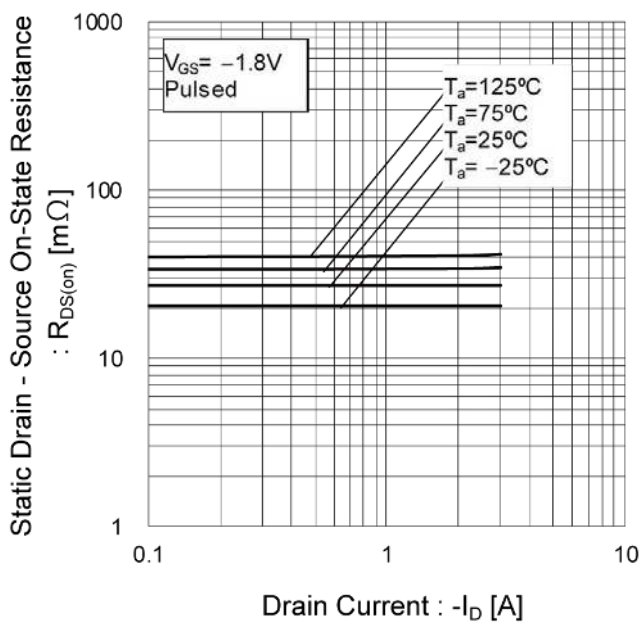
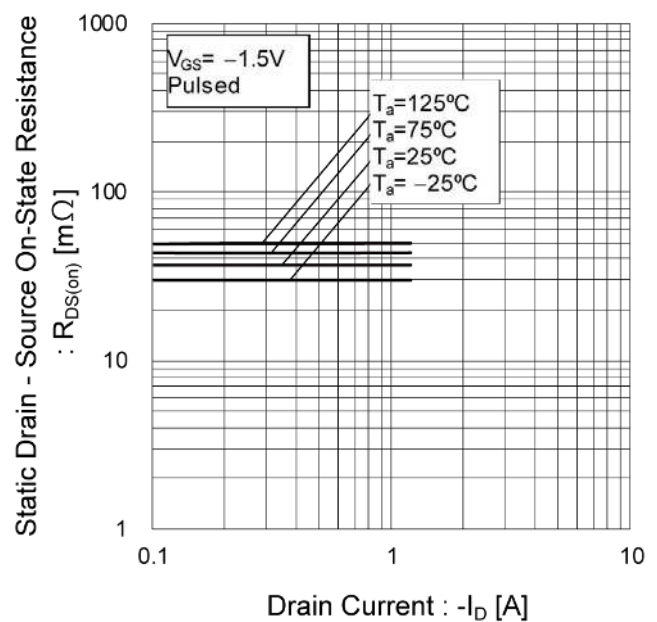


Fig.18 Static Drain - Source On - State Resistance vs. Drain Current (V)



● Electrical characteristic curves

Fig.19 Typical Capacitance vs. Drain - Source Voltage

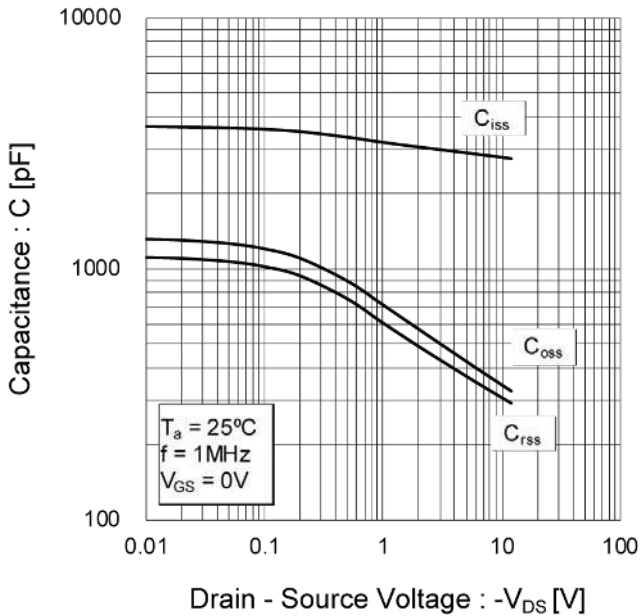


Fig.20 Switching Characteristics

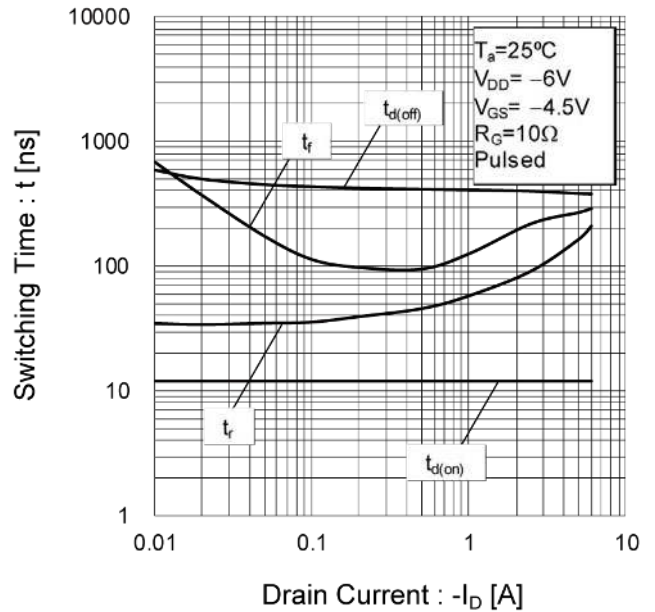


Fig.21 Dynamic Input Characteristics

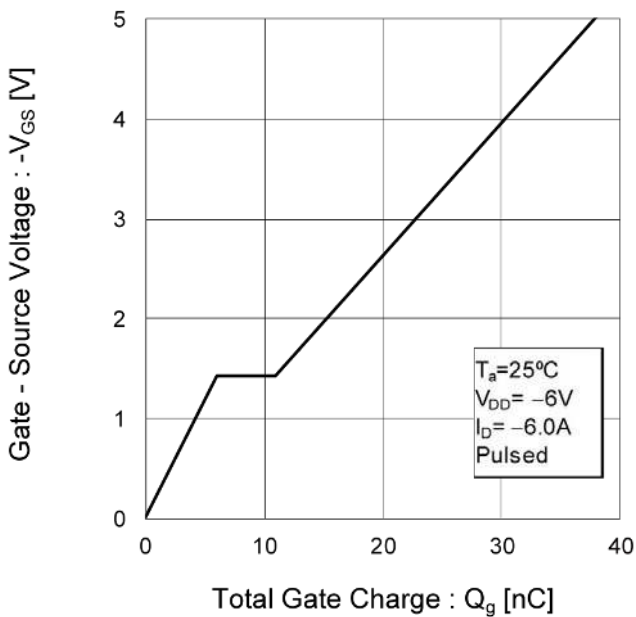
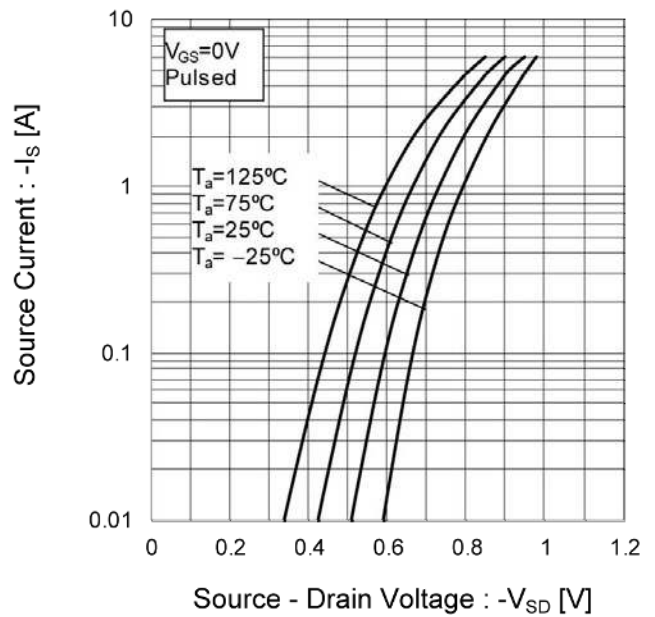


Fig.22 Source Current vs. Source Drain Voltage



● Measurement circuits

Fig. 1-1 SWITCHING TIME MEASUREMENT CIRCUIT

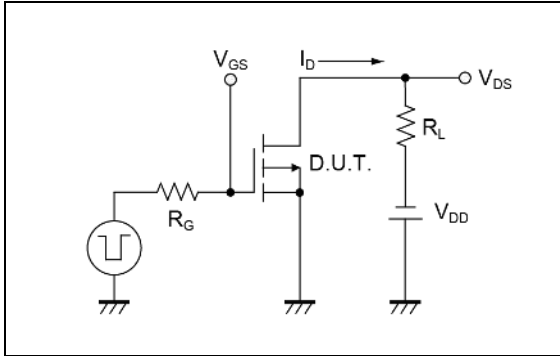


Fig. 1-2 SWITCHING WAVEFORMS

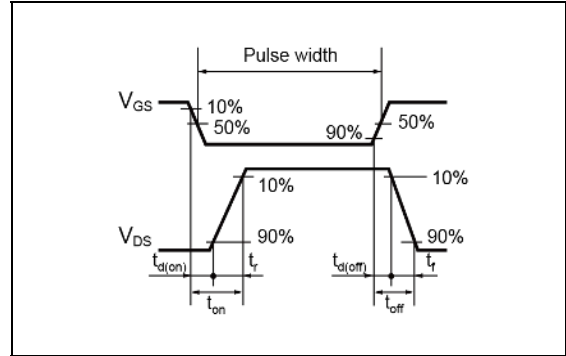


Fig. 2-1 GATE CHARGE MEASUREMENT CIRCUIT

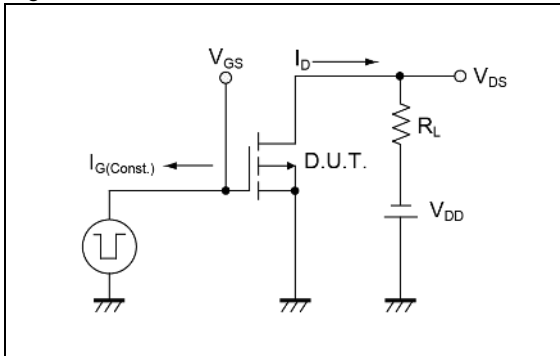
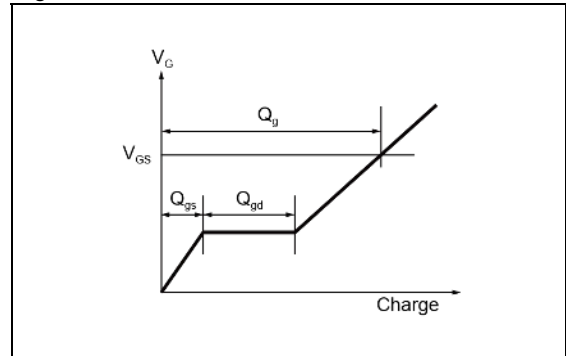


Fig. 2-2 GATE CHARGE WAVEFORM

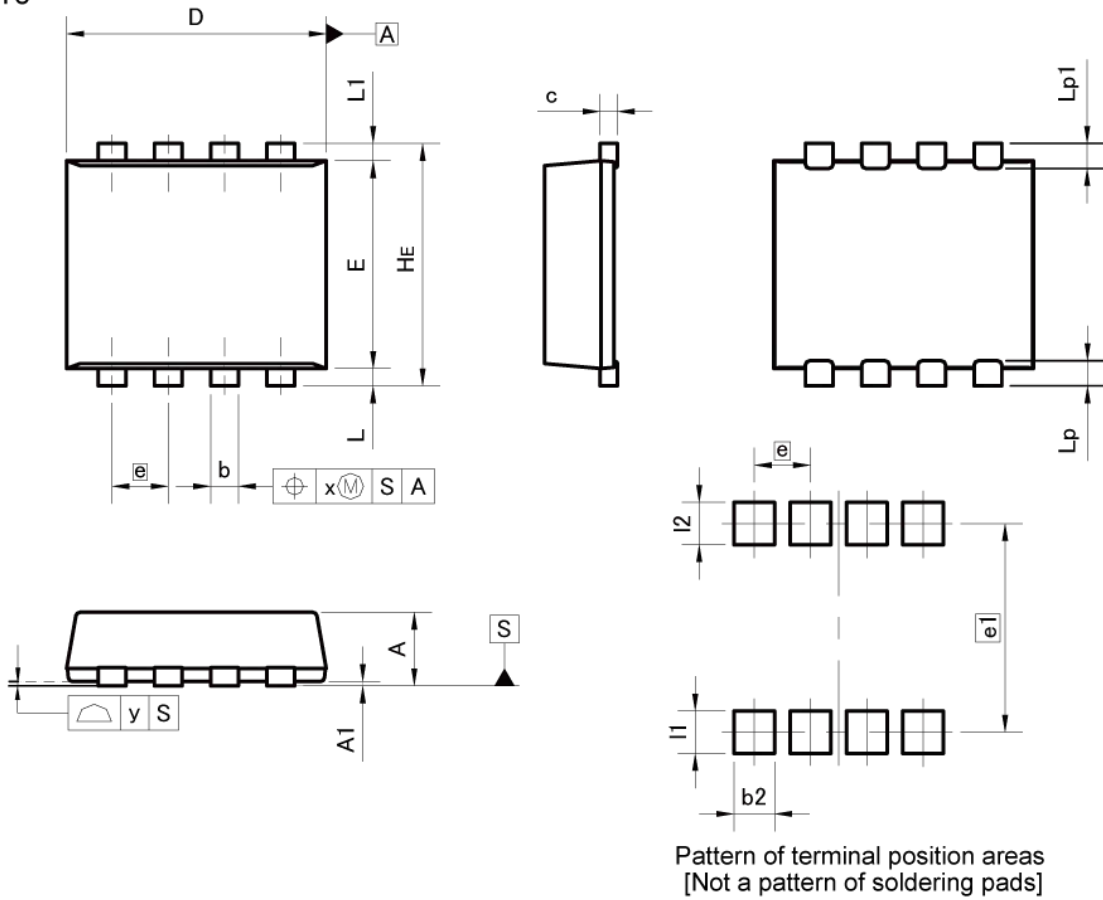


● Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

●Dimensions

TSMT8



| DIM | MILIMETERS | | INCHES | |
|-----|------------|------|--------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.75 | 0.85 | 0.030 | 0.033 |
| A1 | 0.00 | 0.05 | 0.000 | 0.002 |
| b | 0.27 | 0.37 | 0.011 | 0.015 |
| c | 0.12 | 0.22 | 0.005 | 0.009 |
| D | 2.90 | 3.10 | 0.114 | 0.122 |
| E | 2.30 | 2.50 | 0.091 | 0.098 |
| e | 0.65 | | 0.026 | |
| HE | 2.70 | 2.90 | 0.106 | 0.114 |
| L | 0.10 | 0.30 | 0.004 | 0.012 |
| L1 | 0.10 | 0.30 | 0.004 | 0.012 |
| Lp | 0.19 | 0.39 | 0.007 | 0.015 |
| Lp1 | 0.19 | 0.39 | 0.007 | 0.015 |
| x | - | 0.10 | - | 0.004 |
| y | - | 0.10 | - | 0.004 |

| DIM | MILIMETERS | | INCHES | |
|-----|------------|------|--------|-------|
| | MIN | MAX | MIN | MAX |
| b2 | - | 0.47 | - | 0.019 |
| e1 | 2.41 | | 0.095 | |
| l1 | - | 0.49 | - | 0.019 |
| l2 | - | 0.49 | - | 0.019 |

Dimension in mm/inches

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